NSN 5962-00-434-3137



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-00-434-3137 **Body Outside Diameter:** 0.550 inches **Body Height:** Between 0.050 inches and 0.070 inches **Maximum Power Dissipation Rating:** 150.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and hermetically sealed and w/enable **Inclosure Material:** Glass and metal **Inclosure Configuration:** Flat pack **Output Logic Form:** P-type metal oxide-semiconductor logic **Input Circuit Pattern:** 5 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 0.3 volts power source **Time Rating Per Chacteristic:** 80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Precious Material:** Gold **Test Data Document:** 13499-351-8104 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 22 flat leads Shelf Life: N/a **Unit Of Measure:**

Fiig: A458a0

Demilitarization: Yes - demil/mli